

## NCE P-Channel Enhancement Mode Power MOSFET

## **Description**

The NCE20P05Y uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a load switch or in PWM applications.

#### **General Features**

•  $V_{DS} = -20V, I_{D} = -5A$ 

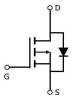
 $R_{DS(ON)}$  < 25m $\Omega$  @  $V_{GS}$ =-4.5V

 $R_{DS(ON)}$  < 40m $\Omega$  @  $V_{GS}$ =-2.5V

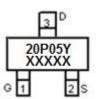
- High power and current handing capability
- Lead free product is acquired
- Surface Mount Package

### **Application**

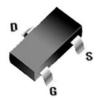
- Motor drive
- Load switch
- Power management



Schematic diagram



Marking and pin Assignment



SOT-23-3L top view

## **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
20P05Y	NCE20P05Y	SOT23-3L	Ø180mm	8mm	3000 units

## Absolute Maximum Ratings (T<sub>A</sub>=25 ℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	-20	V
Gate-Source Voltage	V <sub>G</sub> s	±12	V
Drain Current-Continuous	I <sub>D</sub>	-5	Α
Drain Current-Pulsed (Note 1)	I <sub>DM</sub>	-20	А
Maximum Power Dissipation	P <sub>D</sub>	1.5	W
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 150	°C

## **Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ heta JA}$	83.3	°C/W

#### Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =-250µA	-20	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-20V,V <sub>GS</sub> =0V	-	-	-1	μΑ



# http://www.ncepower.com

# NCE20P05Y

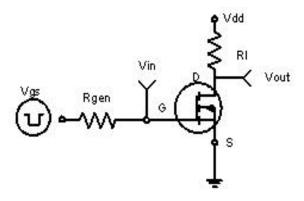
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±12V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)	•		•			
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =-250µA	-0.5	-0.7	-1.4	V
Drain Source On State Begintance	В	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-5A	-	20	25	mΩ
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-5A		30	40	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =-5V,I <sub>D</sub> =-5A	-	17	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C <sub>lss</sub>	V <sub>DS</sub> =-10V.V <sub>GS</sub> =0V.	-	2015	-	PF
Output Capacitance	Coss	F=1.0MHz	-	190	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F-1.UIVITZ	-	173	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	4.5	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =-10V, $R_L$ =10 $\Omega$ ,	-	9.2	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =-4.5 $V$ , $R_{GEN}$ =6 $\Omega$	-	18.7	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	3.3	-	nS
Total Gate Charge	Qg		-	15	-	nC
Gate-Source Charge	Qgs	V <sub>DS</sub> =-10V,I <sub>D</sub> =-5A,V <sub>GS</sub> =-4.5V	-	1.8	-	nC
Gate-Drain Charge	Q <sub>gd</sub>		-	2.8	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =-5A	-	-	-1.2	V

### Notes:

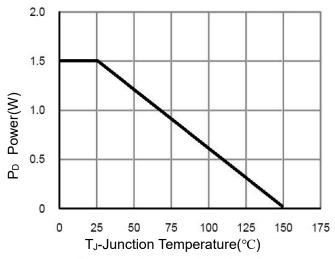
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production



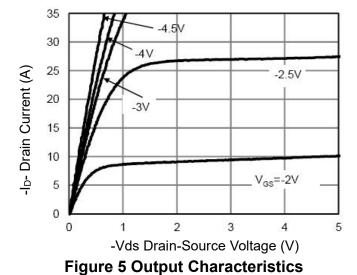
# **Typical Electrical and Thermal Characteristics**



**Figure 1 Switching Test Circuit** 



**Figure 3 Power Dissipation** 



V<sub>OUT</sub>

V<sub>IN</sub>

10%

PULSE WIDTH

t<sub>d(off)</sub>

t<sub>off</sub>

t<sub>off</sub>

t<sub>d(off)</sub>

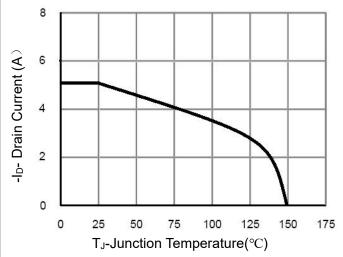
90%

90%

90%

PULSE WIDTH

**Figure 2 Switching Waveforms** 



**Figure 4 Drain Current** 

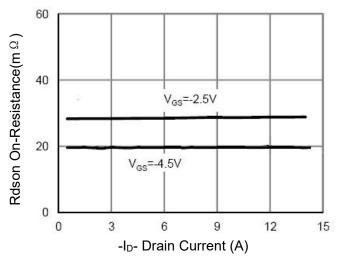
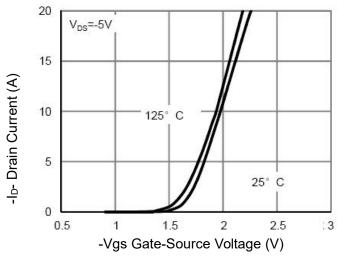


Figure 6 Drain-Source On-Resistance





**Figure 7 Transfer Characteristics** 

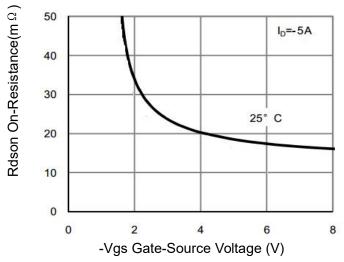
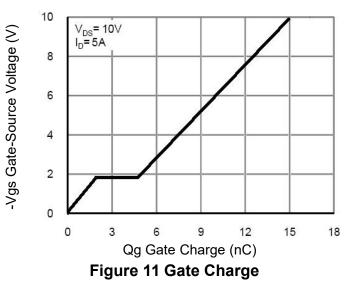


Figure 9 Rdson vs Vgs



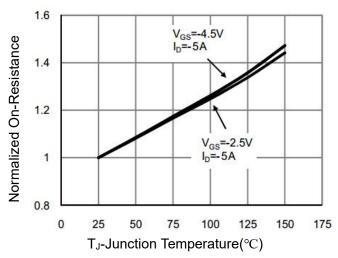


Figure 8 Drain-Source On-Resistance

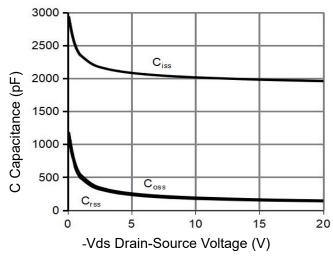


Figure 10 Capacitance vs Vds

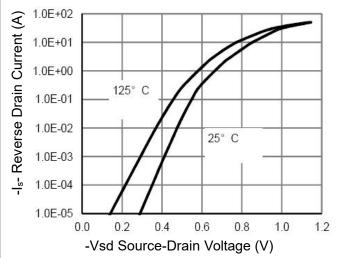
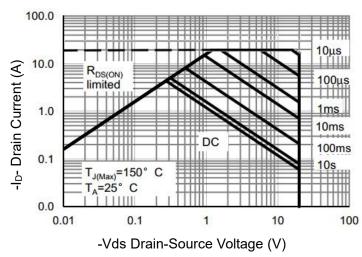
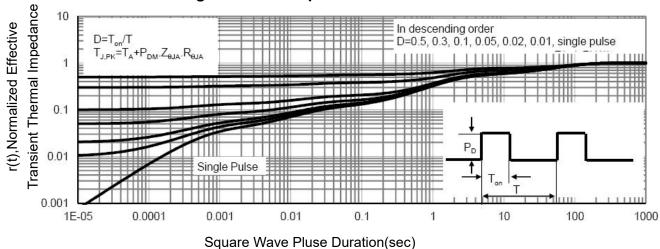


Figure 12 Source- Drain Diode Forward





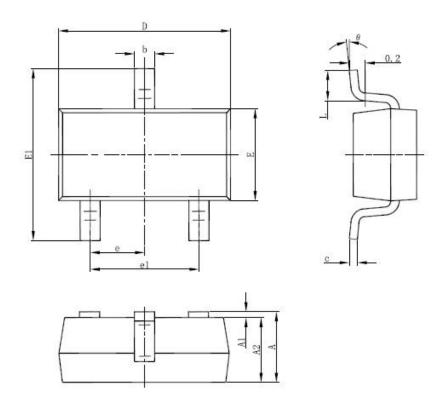
**Figure 13 Safe Operation Area** 



**Figure 14 Normalized Maximum Transient Thermal Impedance** 



# **SOT-23-3L Package Information**



Cumb a I	Dimensions In	Millimeters	Dimensions	In Inches
Symbol	Min	Max	Min	Max
Α	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
С	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
е	0.950(	BSC)	0.037	(BSC)
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

## **Notes**

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- 5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exac



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